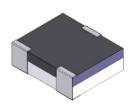


Small Signal Switching Diode

> CDBAV99/CDBAV70/CDBAW56/CDMMBD4148



FEATURES

- Silicon epitaxial planar diode
- SMD chip pattern, dual diode with anode to cathode
- Leadfree and RoHS compliance components

MECHANICAL CHARACTERISTICS

■ Size: SOT-23 case
■ Weight: approx. 21mg

■ Marking: BAV99 as anode to cathode series dual switching diode

BAV70 as common cathode dual switching diode

BAW56 as common anode dual switching diode

BD4148 as SOT-23 case single switching diode

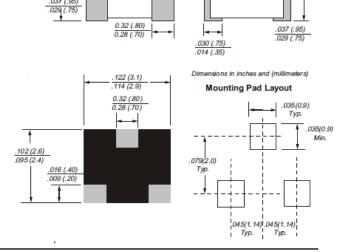
Graphic symbol

<u> </u>			
CDBAV99	CDBAV70	CDBAW56	CDMMBD4148
1 2	1 2	1 2	1 2

DIMENSIONS

Dimension/mm	SOT-23CD
L	3.0±0.1
W	2.5±0.1
Т	0.85±0.1
С	0.55±0.2







THERMAL CHARACTERISTICS¹⁾

Parameter at T _{amb} =25°C ¹⁾	Symbol	Value	Unit
Forward Power Dissipation	D	300	mW
Power derating above 25°C	P _{tot}	2.4	mW/°C
Junction Temperature	T _j	150	°C
Thermal Resistance Junction to Ambient air	$R_{\theta JA}$	430	°C/W
Operating& Storage Temperature range	T _{sta}	-55 to 150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature.

MAXIMUM RATING¹⁾

Parameter at T _{amb} =25°C ¹⁾	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	70	V
Non-Repetitive Peak Reverse Voltage	V_{RSM}	100	V
Average rectified current sin half wave	т	150 ²⁾	mA
rectification with resistive load	$I_{F(AV)}$	130 ³⁾	mA
Repetitive Peak Forward Current at T _{amb} =25°C	I_{FRM}	200	mA
Non-Repetitive Surge Forward Current		500	mΛ
at t<1s and T _j =25°C	${ m I}_{\sf FSM}$	500	mA
at $t \le 8.3$ ms and $T_j = 25$ °C		1000	mA

¹⁾ Valid provided that electrodes are kept at ambient temperature.

ELECTRICAL CHARACTERISTICS¹⁾

Parameter at T _{amb} =25°C ¹⁾	Symbol	Value	Unit
Forward Voltage at I _F =10mA	V	0.855 _{MAX}	V
at I_F =100mA	V_{F}	1.0 _{MAX}	V
Leakage Current at V _R =70V	\mathbf{I}_R	2.5 _{MAX}	uA
Capacitance at VR=6V,f=1MHz	C_{tot}	4 _{MAX}	pF
Reverse Recovery Time at VR=6V I _F	t _{rr}	4 _{MAX}	ns
$=I_R=10$ mA, $R_L=50$ Ω	Чr	→ MAX	113

¹⁾ Valid provided that electrodes are kept at ambient temperature.

²⁾ Single diode loader

³⁾ Double diode loader



TYPICAL CHARACTERISTICS

Figure 1. Forward Characteristic

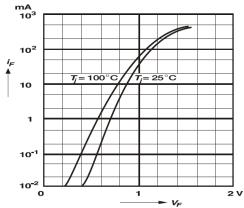


Figure 3. Forward Current De-rating

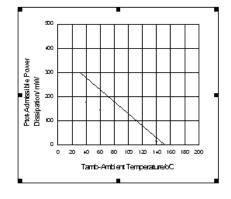
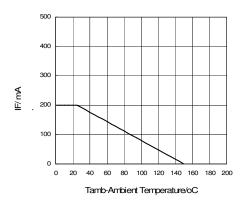
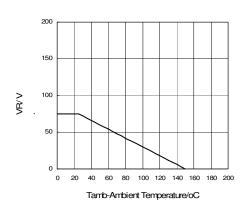


Figure 2. Power De-rating

Figure 4. Reverse Voltage De-rating





TEST CHARACTERISTICS

Test Item	Test Condition	Requirement
Solderability	Sn bath at 245±5°C for 2±0.5s	>95% area tin covered
Resistance to Soldering Heat	Sn bath at 260±5°C for 10±2s	V _F ,V _Z & I _R within spec; no mechanical damage
Humidity Steady State	At 85°C 85%RH for 168hrs	V _F ,V _Z & I _R within spec
Continue Forward Operating Life	At 25°C $I_F = 1.1I_F$ for 1000hrs	V _F ,V _Z & I _R within spec
Thermal Shock	-55 ±5°C/5min to 150±5°C/5min for 10cycles	V _F ,V _Z & I _R within spec

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Bending Strength Bending up to 2mm	for 1 cycle $V_F, V_Z \& I_R$ within spec; no mechanical damage
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APPLICATIONS

- Function: Fast switching
- Soldering Condition:

Soldering Condition & Caution

■ Recommended Soldering Condition (Refer to IPC/JEDEC J-STD-020D 4-1&5.2)

Recommended Profile Condition	Sn-Pb Soldering	Leadfree Soldering	Wave Soldering	
Ramp-up rate (from pre-heat stage)	<3°C/s	<3°C/s	△T<150°C	
Dro host Tomporature & Time	100-150 °C	150-200 °C	100-150 °C	
Pre-heat Temperature & Time	60-120s	60-120s	60-120s	
Coldoring Tomporature 9. Time	183 °C	217 °C	260±5°C	
Soldering Temperature & Time	60-150s	60-150s	5±2s	
Dools Tomporature	230±5°C	245±5°C	260±5°C	
Peak Temperature	<260°C	<260°C	200±5°C	
Time within 5°C of peak temperature	10-20s	20-30s	-	
Ramp-down rate	<6°C/s	<6°C/s	<6°C/s	
Time 25°C to peak temperature	<6min	<8min	-	

Manual Soldering: Approx. 350°C for 3s, avoid solder iron tip direct touch the components body

Recommended Soldering Profile

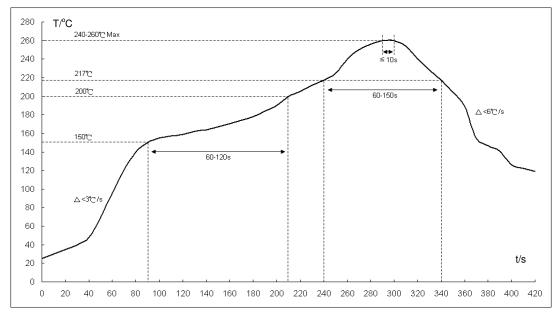


Fig1: Reflow soldering profile for lead-free solder (SnAgCu)



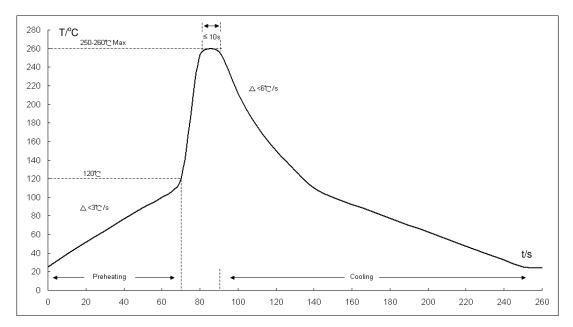


Fig2: Wave soldering profile

- *1. The recommended profiles are referring to IPC/JEDEC J-STD-020D & IEC-60068-2-58
- *2. Chip diodes are able to stand maximum soldering temperature up to 260°C max for 10s, and the soldering cycles with max 3 times, referring to IEC-60068-2-58
- Storage Condition: Product termination solderability can degrade due to high temperature and humidity or chemical environment. Storage condition must be in an ambient temperature of <40°C and ambient humidity of <75%RH, and free from chemical.

ENVIRONMENTAL CHARACTERISTICS

	Hazardous Substance or Element/ppm					
Product	Pb	Cd	Hg	Cr ⁶⁺	PBB	PBDE
	<1000	<100	<1000	<1000	<1000	<1000
	Halogen Substance/ ppm					
Product	F	CI	В	Br	I	Total
	<900	<900) <9	000	<900	<1500

PACKING METHOD

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Product	Quality/Reel	Reel Size	Tape
rroddet	5,000pcs	7"	Embossed tape

DISCLAIMERS

These products are not designed for use in applications where any failure or malfunction may resulted in personal injury, death or severe property or environmental damage such as medical, military, aircraft,

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space or life support equipments.